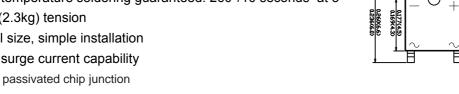


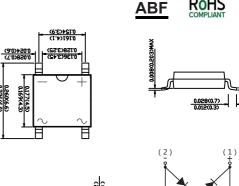
ABF2 THRU ABF10

SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIERS

Features

- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- ♦ High temperature soldering guaranteed: 260°/10 seconds at 5 lbs., (2.3kg) tension
- ♦ Small size, simple installation
- High surge current capability
- Glass passivated chip junction









Mechanical Data

Case: JEDEC ABF Molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Polarity symbol marking on body

Mounting Position: 82mg 0.0029oz

Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unlss otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter Marking Code	SYMBOLS	MDD ABF2	MDD ABF4	MDD ABF6	MDD ABF8	MDD ABF10	UNITS
Maximum repetitive peak reverse voltage	VRRM	200	400	600	800	1000	V
Maximum RMS voltage	VRMS	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	200	400	600	800	1000	V
Maximum average forward rectified current	lf(AV)	1.2				Α	
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	lfsm	40					А
Maximum instantaneous forward voltage drop per leg at 1.2A	VF	1.1					V
Maximum DC reverse current Ta=25°C at rated DC blocking voltage Ta=125°C	I _R	5 100				uA	
Typical thermal resistance	RθJA	70					°C/W
	RθJC	18					
Typical junction capacitance	Cj	18				pF	
Operating temperature range	TJ	-55 to +150				°C	
storage temperature range	Тѕтс	-55 to +150				°C	

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

DN:T21308A1



ABF2 THRU ABF10

Voltage Range - 200 to 1000 V olts Current - 1.2Ampere

Ratings And Characteristic Curves

Fig.1 Average Rectified Output Current Derating Curve

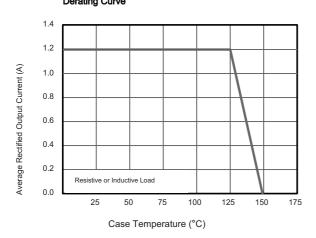


Fig.2 Typical Reverse Characteristics

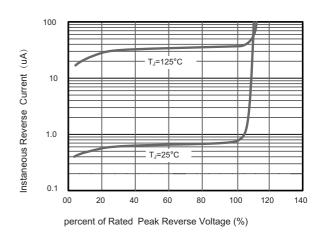


Fig.3 Typical Instaneous Forward
Characteristics T_J=25°C

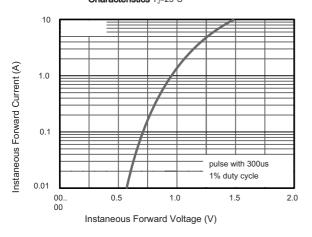


Fig.4 Typical Junction Capacitance

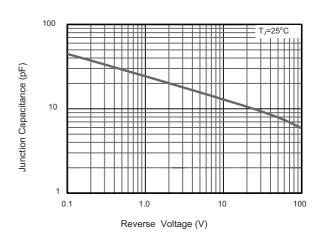
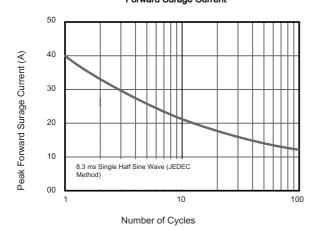


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current



The curve above is for reference only.

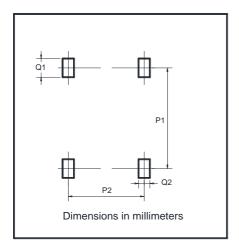
http://www.microdiode.com Rev:2021A1 Page :2



ABF2 THRU ABF10

Voltage Range - 200 to 1000 V olts Current - 1.2 Ampere

Suggested Pad Layout



Dim	Min		
P1	5.72		
P2	4.00		
Q1	1.00		
Q2	0.90		